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NXP SEMICONDUCTORS LTD.

3F., NO. 19-8, SAN CHONG ROAD, NA GANG DISTRICT, TAIPEI 115, TAIWAN

R. O. C.

The following sample(s) was/were submitted and identified by/on behalf of the client as:

Sample Description HERMETICALLY SEALED GLASS (SURFACE-MOUNTED) PACKAGE

SOD80C / SOD27 / SOD66 / SOD86 / SOD87

Sample Receiving Date 2012/02/27

2012/02/27TO2012/03/09 **Testing Period**

Test Result(s) Please refer to next page(s).

Chenyu Kung / Operation Manager Signed for and on behalf of SGS TAIWAN LTD.

Chemical Laboratory - Taipei

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Test Result(s)

PART NAME NO.1 BODY (CE/2009/27288 NO.1)

Test Item (s):	Unit	Method	MDL	Result
				No.1
Cadmium (Cd)	mg/kg	With reference to IEC 62321:2008 and performed by ICP-AES.	2	n.d.
Lead (Pb)	mg/kg	With reference to IEC 62321:2008 and performed by ICP-AES.	2	545000
Mercury (Hg)	mg/kg	With reference to IEC 62321:2008 and performed by ICP-AES.	2	n.d.
Hexavalent Chromium Cr(VI) by	mg/kg	With reference to IEC 62321: 2008	2	n.d.
alkaline extraction		and performed by UV-VIS.		
Sum of PBBs		With reference to IEC 62321: 2008 and performed by GC/MS.	-	n.d.
Monobromobiphenyl			5	n.d.
Dibromobiphenyl			5	n.d.
Tribromobiphenyl	mg/kg		5	n.d.
Tetrabromobiphenyl			5	n.d.
Pentabromobiphenyl			5	n.d.
Hexabromobiphenyl			5	n.d.
Heptabromobiphenyl			5	n.d.
Octabromobiphenyl			5	n.d.
Nonabromobiphenyl			5	n.d.
Decabromobiphenyl			5	n.d.
Sum of PBDEs			-	n.d.
Monobromodiphenyl ether			5	n.d.
Dibromodiphenyl ether			5	n.d.
Tribromodiphenyl ether			5	n.d.
Tetrabromodiphenyl ether			5	n.d.
Pentabromodiphenyl ether			5	n.d.
Hexabromodiphenyl ether			5	n.d.
Heptabromodiphenyl ether			5	n.d.
Octabromodiphenyl ether			5	n.d.
Nonabromodiphenyl ether			5	n.d.
Decabromodiphenyl ether			5	n.d.

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Test Item (s):	Unit	Method	MDL	Result
				No.1
Halogen		With reference to BS EN 14582:2007. Analysis was performed by IC method for F , Cl , Br, I content.		
Halogen-Fluorine (F) (CAS No.: 014762-94-8)	mg/kg	With reference to BS EN 14582:2007. Analysis was performed by IC method for Fluorine content.	50	n.d.
Halogen-Chlorine (CI) (CAS No.: 022537-15-1)	mg/kg	With reference to BS EN 14582:2007. Analysis was performed by IC method for Chlorine content.	50	n.d.
Halogen-Bromine (Br) (CAS No.: 010097-32-2)	mg/kg	With reference to BS EN 14582:2007. Analysis was performed by IC method for Bromine content.	50	n.d.
Halogen-lodine (I) (CAS No.: 014362-44-8)	mg/kg	With reference to BS EN 14582:2007. Analysis was performed by IC method for lodine content.	50	n.d.

Note: 1. mg/kg = ppm; 0.1wt% = 1000ppm

2. n.d. = Not Detected

3. MDL = Method Detection Limit

4. " - " = Not Regulated

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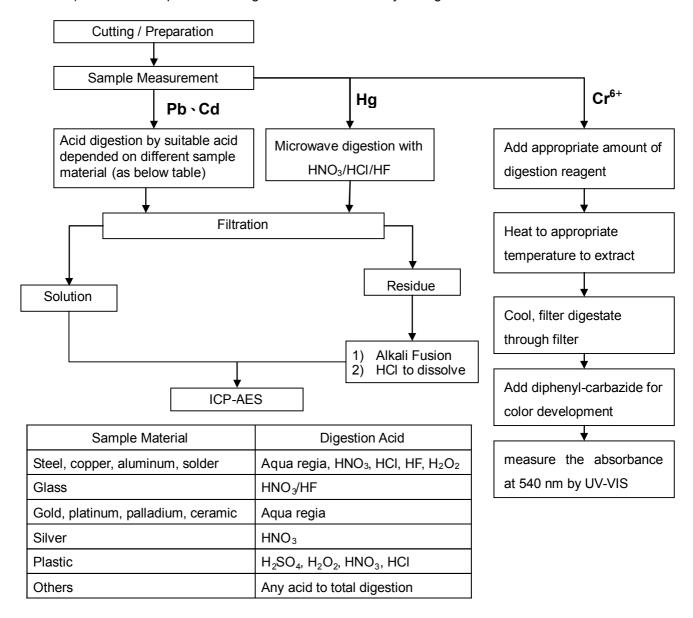


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- 1) These samples were dissolved totally by pre-conditioning method according to below flow chart. (Cr⁶⁺ test method excluded)
- 2) Name of the person who made measurement: Climbgreat Yang
- 3) Name of the person in charge of measurement: Troy Chang



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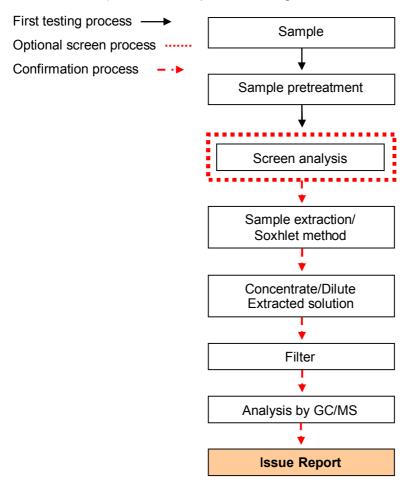
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PBB/PBDE analytical FLOW CHART

- 1) Name of the person who made measurement: Roman Wong
- 2) Name of the person in charge of measurement: Shinjyh Chen



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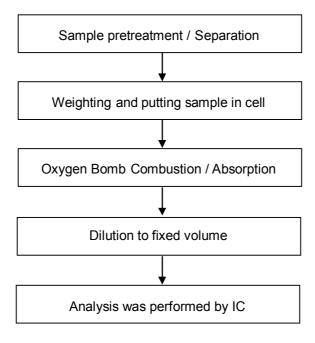
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Analytical flow chart of halogen content

- 1) Name of the person who made measurement: Alan Chen
- 2) Name of the person in charge of measurement: Troy Chang



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** End of Report **

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